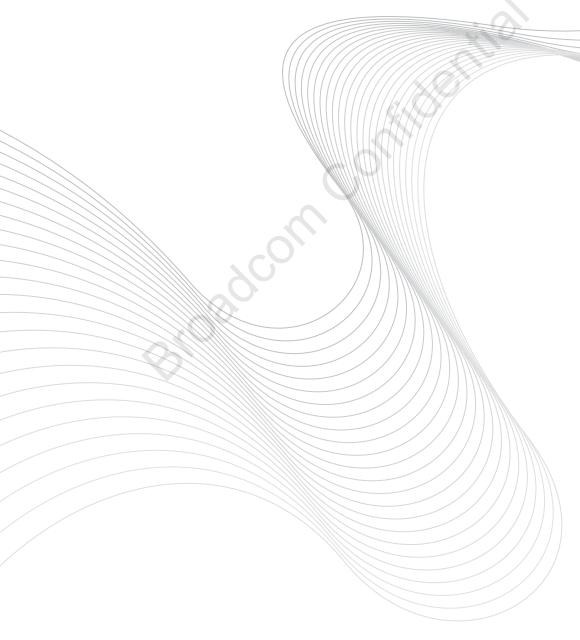


OTP Programming and NVRAM Development in SDIO Mode



Revision History

Revision	Date	Change Description
4339-AN103-R	02/13/14	Updated:
4339-AN103-R	02/13/14	Table 2: "NVRAM Parameters Requiring Customization," on page 14: Changed the subband description for the following NVRAM parameters mcslr5glpo mcsbw205glpo mcsbw405glpo mcsbw805glpo mcslr5gmpo mcsbw205gmpo mcsbw405gmpo mcsbw805gmpo mcslr5ghpo mcslr5ghpo mcsbw805ghpo mcsbw805ghpo mcsbw805ghpo mcsbw805ghpo sb20in40hrpo sb20in80and160hr5glpo sb40and80hr5glpo sb40and80hr5ghpo sb40and80hr5ghpo sb40and80hr5ghpo sb20in80and160hr5ghpo sb40and80hr5ghpo sb20in80and160hr5glpo sb40and80hr5ghpo
		sb20in80and160lr5ghposb40and80lr5ghpo
		- dot11agduphrpo
		- dot11agduplrpo
4339-AN102-R	08/27/2013	Updated:
		 maxp5ga0 description in Table 2 on page 13
		 ofdmlrbw202gpo description in Table 2 on page 13

Revision	Date	Change Description
4339-AN101-R	07/19/2013	 Updated: Table 1: "Broadcom-Specific NVRAM Parameters," on page 11 Table 2: "NVRAM Parameters Requiring Customizing," on page 13 Table 3: "BCM4339 Minimum OTP Binary Map (502 Bytes)," on page 24 "Programming Basic Parameters into OTP Memory" on page 25 Table 6: "Example BCM4339 Minimum OTP Binary Map (502 Bytes)," on page 27 Figure 2: "BCM4339 Hexadecimal OTP Binary Map Template," on page 29 "Programming the OTP Binary Map" on page 29 Table 8: "Broadcom Tuple Subtags," on page 32
4339-AN100-R	04/26/2013	Initial release.
		adcorn Confidentifo.
		Broadcom Corporation

Broadcom Corporation 5300 California Avenue Irvine, CA 92617

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About This Document

Purpose and Audience

This application note describes the method for creating and programming an nvram.txt file. This file is used to test a new board design, optimize NVRAM values, and program the one-time programmable (OTP) nonvolatile memory in the BCM4339 device.

This document is intended for design and applications engineers. It contains information on:

- NVRAM content development and OTP programming flow
- SDIO Windows® XP driver installation
- · Customizing the nvram.txt file
- · OTP programming procedure

Before You Begin

It is recommended that the users of this application note request the following items from Broadcom's Customer Support Portal (CSP):

- A BCM4339 board reference design package that contains:
 - The reference board schematic, bill of materials, and layout. Be sure to specify either the WLBGA or WLCSP package, and either single-band (2.4 GHz only) or dual-band (2.4 GHz and 5 GHz).
 - An nvram.txt template file for the reference board.
- A Windows XP or Linux[®] device driver for the relevant SDIO device
- · Broadcom transmit signal strength indicator (TSSI) calibration tools

Refer to "Technical Support" on page 8 for details on accessing Broadcom CSP. If necessary, contact your Sales or Engineering support representative.

Acronyms and Abbreviations

In most cases, acronyms and abbreviations are defined on first use.

For a comprehensive list of acronyms and other terms used in Broadcom documents, go to: http://www.broadcom.com/press/glossary.php.

Document Conventions

The following conventions may be used in this document:

Convention	Description	
Bold	User input and actions: for example, type exit, click OK, press Alt+C	
Monospace	Code: #include <iostream> HTML: Command line commands and parameters: wl [-1] <command/></iostream>	

Technical Support

Broadcom provides customer access to a wide range of information, including technical documentation, schematic diagrams, product bill of materials, PCB layout information, and software updates through its customer support portal (https://support.broadcom.com). For a CSP account, contact your Sales or Engineering support representative.

In addition, Broadcom provides other product support through its Downloads & Support site (http://www.broadcom.com/support/).

Introduction

The Broadcom[®] BCM4339 is a single-chip IEEE 802.11 a/b/g/n/ac + BT4.0/FM RX device for embedded applications. One-time programmable (OTP) nonvolatile memory is included in the WLAN section of the device to store board-specific information such as product ID, manufacturer ID, MAC address. Excluding the header information, up to 502 bytes of OTP memory is available on the BCM4339 for WLAN information. Although the WLAN section provides the option of using a SDIO or HSIC host interface, this application note addresses only SDIO applications.

The OTP memory content, along with an editable NVRAM file (nvram.txt file), provides a complete card information structure (CIS) used by the device driver to initialize and configure the BCM4339.

OTP Programming Considerations

In designs where the host and device are permanently connected together, which is typically done using a hardwired SDIO interface, programming the OTP memory during production is optional. It is equally acceptable to store all NVRAM parameters in the host firmware and keep the OTP blank in production. For devices that may be installed on different hosts, the OTP memory can be programmed to protect the unique MAC address and prevent end-users from altering the power control parameters such as maximum output power.

It is not necessary to program the OTP memory during board bring-up and hardware tuning on host platforms that run the Linux[®] or Windows[®] XP operating systems. Instead, all required board variables can be stored in the nvram.txt file. Although programming the OTP memory is not required for devices running these host operating systems, the nvram.txt file development is still required.

The initial state of all OTP bits in an unprogrammed device is 0. Individual bits can be set to 1, but once set, they can never be reset to 0. The entire OTP array can be programmed in a single-write cycle using the wl commands provided with the SDIO driver. As an alternative, multiple write cycles can be used to selectively program specific fields. However, only the bits that are still in the 0 state can be set to the 1 state during each programming cycle.

Because the OTP programming process is irreversible, Broadcom recommends that board designers finalize all parameters before programming the OTP memory. Boards and modules should be tested using only the editable nvram.txt file.

The parameters stored in the nvram.txt file are loaded into on-chip RAM by the driver, allowing the chip to be tested even if the OTP memory has not been programmed. This method lets board designers tune the RF components and alter critical parameters using different versions of the nvram.txt file while testing boards. Optionally, a few basic parameters, such as the board type and MAC address, can be programmed into the OTP memory prior to board testing during development. If a parameter is present in both the on-chip OTP memory and the nvram.txt file, the value in the OTP memory takes priority over the value in the nvram.txt file.



Caution! The OTP programming process is irreversible. Broadcom strongly recommends conducting development on boards with blank OTP memory using the parameters provided in the editable nvram.txt file. Do not program the OTP memory until the contents of the nvram.txt file have been verified and the file has been finalized for production use.

NVRAM Content Development and OTP Programming Flow

Figure 1 on page 11 shows the nvram.txt file content development and the OTP memory programming flow. Parameters in the nvram.txt file can be divided into basic and advanced categories. Relevant OTP programming details for each phase are discussed in "Programming OTP Memory" on page 24.



Note: The NVRAM development and OTP programming flow shown in Figure 1 should be conducted on small quantities of boards/modules during the product development stage. Once this process is complete and the production version of the nvram.txt file and OTP memory file is approved for production use, programming can be begin for high volume mass production as defined by each manufacturer.

Start with an SDIO board with blank OTP memory. **NVRAM Customization** Customize the nyram.txt to match the board RF architecture. Program only the minimum OTP map with the basic NVRAM parameters into OTP. Optional Basic Parameters Programming Install board with customized NVRAM. Verify OTP. Is the OTP correct? Yes Test the design against specifications. Tune the board components and optimize nvram.txt contents until board meets EVM, spectral mask, sensitivity, and other performance specifications. Run TSSI calibration on the final design to generate the PA parameters. Design and Development Customize the NVRAM with PA parameters and TX output power-related parameters. Freeze the nyram.txt file contents. No Does the design meet specifications? Yes Complete OTP programming with the Advanced Parameters Programming advanced parameters.

Figure 1: NVRAM Development and OTP Programming Flow

Customizing the nvram.txt File

This section describes customizing, editing, and finalizing the nvram.txt file for OTP memory programming.

Using the nvram.txt File Template

For each Broadcom reference board design, Broadcom provides an nvram.txt file for the specific board design. Typically, the file is named in accordance with the board it supports (for example, bcm4339wlcsp.txt).

The nvram.txt file might be included with the reference board design package or the driver release. The latest version of the file can be downloaded from the Broadcom CSP (see "Technical Support" on page 7).



Note: When the nvram.txt file is edited, the file must be saved and the wireless device driver must be disabled and reenabled in Windows Device Manager for the change to take effect. Save the file as nvram.txt and store it in the C:\Windows\system32\drivers\ directory. Delete or overwrite any previous version of the file located in this directory.

Table 1 and Table 2 on page 14 provide a list of parameters in a typical nyram.txt file that are common to Broadcom dual-band SDIO reference design boards.

Parameters in the nvram.txt file do no need to be entered in any specific order.



The parameters listed in Table 1 are used and specified by Broadcom-specific and should not be changed.

Table 1: Broadcom-Specific NVRAM Parameters

NVRAM Parameter	Example Data	Description	
sromrev	11	SROM revision for IEEE 802.11ac chips	
boardrev	0x1100	Board revision tracked by the used by the WLAN driver.	
		Examples:	
		0x1100 corresponds to P100	
		0x1208 corresponds to P208	
boardtype	0x696	Identifies the board for testing purposes.	
		Contact a Broadcom sales or technical support representative for details. See "Technical Support" on page 7 for contact information.	
tssipos2g	1	Defines the slope of the 2.4 GHz Transmission Signal Strength Indicator (TSSI).	
		0 = Negative slope	
		1 = Positive slope (setting for all BCM4339 devices)	
tssipos5g	1	Defines 5 GHz TSSI slope.	
		0 = Negative slope	
		1 = Positive slope (setting for all BCM4339 devices)	

Table 1: Broadcom-Specific NVRAM Parameters (Cont.)

only.	
1 = Diversity NVRAM revision. Note: This parameter is for Broadcom internal use only. Vendor ID Chip ID 4339 Manufacturer ID Flag for checking CRC. Check CRC error when loading firmware.	

The design variables listed in Table 2 on page 14 must be reviewed prior to beginning board or module testing. Specifically, the boardflags and swctrlmap variables and the number of antennas must be customized to match the board's RF architecture. During the development phase, start with the default power amplifier (PA) parameters contained in the provided nvram.txt file. The PA parameters are eventually optimized using Broadcom TSSI calibration tools.



Note: The parameters in Table 2 typically require tuning for each specific-board or module design. This is not an exhaustive list. Additional parameters may be added by Broadcom at any time to control the RF performance-related attributes of the driver. Always check with Broadcom for the latest version of the nvram.txt file for the reference design before starting for any board customization efforts.



Note: To avoid unexpected operating results, contact a technical support representative before attempting to add NVRAM parameters.

Table 2: NVRAM Parameters Requiring Customization

NVRAM Parameter	Example Data	Description
boardflags	0x10401001	Board configuration flag that defines the power
boardflags2	0x0	topology, external components (ePA, eLNA), etc.
boardflags3	0x810c48c	
ccode	0	The country code (ccode) parameter is for regulatory use and specifies which regulatory tables are to be loaded.
		Note: Together, the ccode and regrev parameters set the power limitations necessary to meet the country-specific regulatory specifications.
regrev	0	The regulatory revision (regrev) code parameter is for regulatory use and specifies which regulatory tables are to be loaded.
		Note: Together, the regrev and ccode parameters set the power limitations necessary to meet the country-specific regulatory specifications.
pdgain5g pdgain2g	1	Power detector parameter used by the driver to program the TSSI loopback path.
tworangetssi2g tworangetssi5g	0	TSSI dual power range flag (which iPA chips support).
femctrl	4	This parameter defines the front-end RF switch or front-end module (FEM) control logic for both bands.
xtalfreq	37400	This parameter describes the reference oscillator frequency (kHz).
extpagain2g	1	This parameter enables support for the 2.4 GHz external PA.
extpagain5g	1	This parameter enables support for the 5 GHz external PA.
rxgains2gelnagaina0	3	This parameter defines the 2G eLNA gain (dB).
rxgains2gtrisoa0	3	This parameter defines the isolation that the TR switch provides when in "T" mode (or the isolation provided in external LNA bypass mode) for core 0.
rxgains2gtrelnabypa0	1	This parameter defines the isolation that eLNA provides in Bypass mode.
rxgains5gelnagaina0	3	This parameter defines the 5G eLNA gain (dB)
rxgains5gtrisoa0	4	This parameter defines the isolation that the TR switch provides when in "T" mode (or the isolation provided in external LNA bypass mode) for core 0.
rxgains5gtrelnabypa0	1	This parameter defines the isolation that eLNA provides in Bypass mode.
aa2g	1	This parameter specifies the number of antennas
aa5g		available for the 2.4 GHz and 5 GHz bands, respectively, in bit-mapped binary format:
		1 = 01b for one antenna
		3 = 11b for two antennas

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
agbg0 aga0	0x82	Antenna gain (dBi) is defined by converting its hexadecimal value to 8-bit binary, then follow the following rule:
		Lower 0 – 5 bits: 6-bit signed 2's complement number in whole dB units.
		Higher 6 – 7 bits:2-bit unsigned number in quarter dB units.
		Examples:
		$0x82 (10000010) = 2.5 dB (2 + 2 \times 0.25)$
		$0x7f(011111111) = -0.75 dB(-1 + 1 \times 0.25)$
pa2ga0 pa2gccka0	–148 , 5828, –679	The PA parameters for the 2.4 GHz band based on TSSI calibration.
		Note: The pa2ga0 parameter is for the Orthogonal Frequency Division Multiplexing (OFDM) and MCS rates. The pa2gccka0 parameter for the CCK rate.
pa5ga0 pa5gbw40a0 pa5gbw80a0	83, 6045, -553, 57, 5940, -566, 12, 5919, -605, -17, 5899, -640	The PA parameters for the 5 GHz band are based on TSSI calibration (Low/Mid/High/X1) (subband5gver = 4).
pasgbwooau		Subband Frequency RangeChannel Range
		Low:5180 to 524036 to 48
		Mid:5260 to 532052 to 64
		High:5500 to 5700100 to 140
		X1: 5745 to 5825149 to 165
		Note: The pa5ga0 parameter is for 20 MHz BW. The pa5gbw40a0 parameter is for 40 MHz BW. The pa5gbw80a0 parameter is for the 80 MHz bandwidth.
		Note: Each of the four subbands has three parameters (total of twelve parameters).
maxp2ga0	0x46	This parameter defines the maximum output power for the 2.4 GHz band in hexadecimal format (quarter dB units).
0		This value applies to all complementary code keying (CCK) rates measured at the antenna port. The nominal target power (dBm) for CCK packets is –1.5 dB from maxp2ga0 (converted in dB units).
		Note: The value can be entered in either hexadecimal or decimal format.
		In the example shown for $0x46$, maximum output power is 17 dBm ((16 x 4 + 6)/4). Nominal output power is 15.5 dBm (17 – 1.5).
cckbw202gpo	0x0000	CCK power offsets for 20 MHz rates
		(11, 5.5, 2, 1 Mbps)
cckbw20ul2gpo	0x0000	CCK power offsets for 20 U/L rates
		(11, 5.5, 2, 1 Mbps)
dot11agofdmhrbw202gpo	0x6666	OFDM power offset (in half dBm units) 54M/48/36M/24M

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
ofdmlrbw202gpo	0x0033	OFDM power offset (in half dBm units)
		MCS1 and MCS2:11n and 11ac 40M
		MCS1 and MCS2:11n and 11ac 20M
		12 and 18 Mbps:11g
		6 and 9 Mbps:11g
mcsbw202gpo	0xAA886664	11n/ac MCS0/1/2, 3-7, C8,C9 power offset (in half dBm units)
		C9/C8/M7/M6/M5/M4/M3/M0-2
maxp5ga0	0x4A, 0x4A, 0x4A, 0x4A	This parameter defines the maximum output power for the 5 GHz band in hexadecimal format (quarter dB units).
		Theses values apply to all legacy OFDM rates measured at antenna port. The nominal target power is –1.5 dB from maxp5ga0 (converted in dB units).
		Note: Values can be entered in either hexadecimal or decimal format.
mcslr5glpo	0x0000	5G low subband 11ag/11n/11ac QPSK power offset with respect to BPSK:
		MCS 1/2 with respect to MCS 0/1/2
		12/18 Mbps with respect to 6/9 Mbps
		LSB to MSB nibble:
		(0) 20 MHz
		(1) 40 MHz
		(2) 80 MHz
		(3) 160 MHz
mcsbw205glpo	0xAA886664	5G low subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 20 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw405glpo	0xAA886664	5G low subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 40 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw805glpo	0xAA886664	5G low subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 80 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw805glpo	0xAA886664	5G low subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 80 MHz

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
mcslr5gmpo	0x0000	5G mid subband 11ag/11n/11ac QPSK power offset with respect to BPSK:
		MCS 1/2 with respect to MCS 0/1/2
		12/18 Mbps with respect to 6/9 Mbps
		LSB to MSB nibble:
		(0) 20 MHz
		(1) 40 MHz
		(2) 80 MHz
		(3) 160 MHz
mcsbw205gmpo	0xAA886664	5G mid subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 20 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw405gmpo	0xAA886664	5G mid subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 40 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw805gmpo	0xAA886664	5G mid subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 80 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcslr5ghpo	0x0000	5G high and X1 subband 11ag/11n/11ac QPSK power offset with respect to BPSK:
		MCS 1/2 with respect to MCS 0/1/2
		12/18 Mbps with respect to 6/9 Mbps
		LSB to MSB nibble:
		(0) 20 MHz
		(1) 40 MHz
		(2) 80 MHz
		(3) 160 MHz
mcsbw205ghpo	0xAA886664	5G high and X1 subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 20 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw405ghpo	0xAA886664	5G high and X1 subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 40 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2
mcsbw805ghpo	0xAA886664	5G high and X1 subband 11n/ac MCS0/1/2, 3-7, C8, C9 power offset for 80 MHz
		C9/C8/M7/M6/M5/M4/M3/M0-2

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
sb20in40hrpo	0xAA886664	20 in 40 OFDM signed power offsets with respect to 20 in 20 for 64 QAM and above.
		LSB nibble to MSB nibble:
		(0) 2G band
		(1) 5G low subband
		(2) 5G mid subband
		(3) 5G high and X1 subband
sb20in80and160hr5glpo	0xAA886664	5G low subband 20 in 80, 20 in 160 OFDM signed power offsets for 64 QAM and above.
		LSB nibble to MSB nibble:
		(0) 20 in 80 with respect to 20 in 20
		(1) 20 in 160 with respect to 20 in 20
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands
sb40and80hr5glpo	0xAA886664	5G low subband 40 in 80, 40 in 160 OFDM signed power offsets for 64 QAM and above.
		LSB nibble to MSB nibble:
		(0) 40 in 80 with respect to 40 in 40
		(1) 40 in 160 with respect to 40 in 40
		(2) 80 in 160 with respect to 80 in 80
		(3) 40 in 160 – 40LL/UU with respect to 40LU/UL
sb20in80and160hr5gmpo	0xAA886664	5G mid subband 20 in 80, 20 in 160 OFDM signed power offsets for 64 QAM and above.
		LSB nibble to MSB nibble:
		(0) 20 in 80 with respect to 20 in 20
		(1) 20 in 160 with respect to 20 in 20
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands
sb40and80hr5gmpo	0xAA886664	5G mid subband 40 in 80, 40 in 160 OFDM signed power offsets for 64 QAM and above.
		LSB nibble to MSB nibble:
		(0) 40 in 80 with respect to 40 in 40
		(1) 40 in 160 with respect to 40 in 40
		(2) 80 in 160 with respect to 80 in 80
		(3) 40 in 160 – 40LL/UU with respect to 40LU/UL

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description		
sb20in80and160hr5ghpo	0xAA886664	5G high and X1 subband 20 in 80, 20 in 160 OFDM signed power offsets for 64 QAM and above.		
		LSB nibble to MSB nibble:		
		(0) 20 in 80 with respect to 20 in 20		
		(1) 20 in 160 with respect to 20 in 20		
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL		
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands		
sb40and80hr5ghpo	0xAA886664	5G high and X1 subband 40 in 80, 40 in 160 OFDM signed power offsets for 64 QAM and above.		
		LSB nibble to MSB nibble:		
		(0) 40 in 80 with respect to 40 in 40		
		(1) 40 in 160 with respect to 40 in 40		
		(2) 80 in 160 with respect to 80 in 80		
		(3) 40 in 160 – 40LL/UU with respect to 40LU/U		
sb20in40lrpo	0xAA886664	20 in 40 OFDM signed power offsets with respect to 20 in 20 for 16 QAM and below.		
		LSB nibble to MSB nibble:		
		(0) 2G band		
		(1) 5G low subband		
		(2) 5G mid subband		
		(3) 5G high and X1 subband		
sb20in80and160lr5glpo	0xAA886664	5G low subband 20 in 80, 20 in 160 OFDM signed power offsets for 16 QAM and below.		
		LSB nibble to MSB nibble:		
		(0) 20 in 80 with respect to 20 in 20		
		(1) 20 in 160 with respect to 20 in 20		
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL		
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands		
sb40and80lr5glpo	0xAA886664	5G low subband 40 in 80, 40 in 160 OFDM signed power offsets for 16 QAM and below.		
		LSB nibble to MSB nibble:		
		(0) 40 in 80 with respect to 40 in 40		
		(1) 40 in 160 with respect to 40 in 40		
		(2) 80 in 160 with respect to 80 in 80		
		(3) 40 in 160 – 40LL/UU with respect to 40LU/UL		

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
sb20in80and160lr5gmpo	0xAA886664	5G mid subband 20 in 80, 20 in 160 OFDM signed power offsets for 16 QAM and below. LSB nibble to MSB nibble:
		(0) 20 in 80 with respect to 20 in 20
		(1) 20 in 160 with respect to 20 in 20
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands
sb40and80lr5gmpo	0xAA886664	5G mid subband 40 in 80, 40 in 160 OFDM signed power offsets for 16 QAM and below.
		LSB nibble to MSB nibble:
		(0) 40 in 80 with respect to 40 in 40
		(1) 40 in 160 with respect to 40 in 40
		(2) 80 in 160 with respect to 80 in 80
		(3) 40 in 160 – 40LL/UU with respect to 40LU/UL
sb20in80and160lr5ghpo	0xAA886664	5G high and X1 subband 20 in 80, 20 in 160 OFDM signed power offsets for 16 QAM and below.
		LSB nibble to MSB nibble:
		(0) 20 in 80 with respect to 20 in 20
		(1) 20 in 160 with respect to 20 in 20
		(2) 20 in 80 – 20LL/UU with respect to 20LU/UL
		(3) 20 in 160 – 20LLL/UUU with respect to other 20 in 160 subbands
sb40and80lr5ghpo	0xAA886664	5G high and X1 subband 40 in 80, 40 in 160 OFDM signed power offsets for 16 QAM and below.
		LSB nibble to MSB nibble:
		(0) 40 in 80 with respect to 40 in 40
		(1) 40 in 160 with respect to 40 in 40
		(2) 80 in 160 with respect to 80 in 80
		(3) 40 in 160 – 40LL/UU with respect to 40LU/UL

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
dot11agduphrpo	0xAA886664	11a/g Duplicate mode signed power offsets for 64 QAM. Common power offset for:
		 Dup40, Dup40 in 80, and Dup40 in 160 with respect to 40 in 40 11n/11ac
		 Quad80 and Quad80 in 160 with respect to 11ac 80in80
		 Oct160 with respect to 11ac 160 in 160
		LSB to MSB nibble:
		(0) 2G band
		(1) 5G low subband
		(2) 5G mid subband
		(3) 5G high and X1 subband
dot11agduplrpo	0xAA886664	Bits 11a/g duplicate mode signed power offsets for 16 QAM and below.
		Common power offset for:
		 Dup40, Dup40 in 80, and Dup40 in 160 with respect to 40 in 40 11n/11ac
		 Quad80 and Quad80 in 160 with respect to 11ac 80in80
		Oct160 with respect to 11ac 160 in 160
		LSB to MSB nibble:
		(0) 2G band
		(1) 5G low subband
	60	(2) 5G mid subband
	20	(3) 5G high and X1 subband
tssifloor2g	245	The tssifloor2g parameter is used to avoid runaway power control (pwrctrl) conditions that can occur when an overtemperature condition exists.
<	3,60	The target power is the minimum power read using NVRAM and the power corresponding to the TSSI floor.
tssifloor5g	220, 213, 218, 228	The tssifloor5g parameter is used to avoid runaway power control (pwrctrl) conditions that can occur when an overtemperature exists.
		The target power is the minimum power read using NVRAN and the power corresponding to the TSSI floor.
rpcal2g	0x0000	Defines 2G Edge channel power compensation (CH12/CH 3/CH 2/CH 1) qdBm unit; 2's compliment
		 B[15:12]: Ch-12 offset
		• B[11:8]: Ch-3
		• B[7:4]: Ch-2
		B[3:0]: Ch-1 offset

Table 2: NVRAM Parameters Requiring Customization (Cont.)

NVRAM Parameter	Example Data	Description
rpcal5gb0	0x0000	2G Edge channel power compensation (CH5/CH4/CH14/CH 13) qdBm unit; 2's compliment
		 B[15:12]: Ch-5 offset
		 B[11:8]: Ch-4
		 B[7:4]: Ch-14
		 B[3:0]: Ch-13 offset
rpcal5gb1	0x0000	2G channel power compensation (CH9/CH8/CH7/CH6) qdBm unit; 2's compliment
		 B[15:12]: Ch-9 offset
		 B[11:8]: Ch-8
		• B[7:4]: Ch-7
		 B[3:0]: Ch-6 offset
rpcal5gb2	0x0000	2G Edge channel power compensation (NA/NA/CH11/CH 10) qdBm unit; 2's compliment
		 B[15:12]: NA offset
		• B[11:8]: NA
		 B[7:4]: Ch-11
		 B[3:0]: Ch-10 offset
cckdigfilttype	2	The cckdigfilttype parameter is used to optimize the spectrum mask and EVM in the IEEE 802.11b mode.
phycal_tempdelta	25	This parameter specifies the temperature delta (°C) at which when exceeded a calibration routine is initiated (temperature ranges between 0 and 63 °C).
txidxcap2g	0	PA maximum input level protection for 2G.
		Minimum 2G txgaintbl index. Gain table entries below this level are blanked.
txidxcap5g	0	PA maximum input level protection for 2G.
		Minimal 5G txgaintbl index. Gain table entries below this level are blanked.
rssicorrnorm_c0	-2, 0	Core 0 only: The rssicorrnorm_c0 parameter adds a specified offset to the raw RSSI value. The final RSSI value comprises the raw RSSI value plus the offset.
		For example, the first value is applied to the 20 MHz channels. The second value is applied to the 40 MHz channels. (20M/40M)

NVRAM Parameter Example Data Description rssicorrnorm5g_c0 2, 3, 0 Core 0 only: The rssicorrnorm5g_c0 parameter adds a specified offset in the raw RSSI value. 1, 1, -1The final RSSI value comprises the raw RSSI value -2, 0, -2plus the offset. The first three values are respectively -2, 0, -2applied to the 20, 40 and 80 MHz channels of the first 5G subband. The next three values are applied to the second subband, and so on. For example, the first value is for subband 1/20 MHz and last value is applied to subband 4/80 MHz. (Low 20/Low 40/Low 80/Mid 20/Mid 40/Mid 80/High 20/High 40/High 80/X1 20/X1 40/X1 80)

Table 2: NVRAM Parameters Requiring Customization (Cont.)

Editing the nvram.txt File

The nvram.txt file should be edited using a properly formatted text editor such as Notepad++ or WordPad++ to preserve the original format of the file. Using a non-formatted text editor such as Notepad could corrupt the format of the NVRAM map, causing the driver to incorrectly read the nvram.txt file.

Finalizing the nvram.txt File

After the final PA parameters have been generated, edit the nvram.txt file to update the PA parameters derived using the Broadcom TSSI tool, and then adjust the Tx output power-related parameters in the file. Using the updated nvram.txt file, run output power tests to verify that the parameters are providing the correct output power. Also, verify that RF performance (EVM, spectral mask, and rxper) meets design specifications.

Broadcom recommends running a regulatory prescan to verify that the required output power can be delivered without violating the band-edge limits. If the band-edge limits cannot be met, it may be necessary to reduce the output power at the band-edge channels.

After all prototype tests have passed and all nvram.txt file parameters have been optimized and finalized, the needed parameters can be selected and the OTP memory programmed for production.

The BCM4339 has 502 bytes of space in the OTP memory available for user data. Given the limited space in the OTP memory, it is impossible to program the entire nvram.txt file to the OTP memory. The programmer must be very careful to select only the necessary parameters that go into the OTP memory. Parameters that typically go into the OTP memory are those that are unique to the board (such as MAC address) and those that are required to satisfy local regulatory requirements, which are usually output power-related parameters such as maximum output power, power offset per-rate, PA parameters, and country code.

Programming OTP Memory

Prior to programming the OTP memory, an OTP binary map file must be prepared and populated with the correct values. The OTP binary map completely defines the parameters that have to be programmed into the OTP memory. The SDIO OTP data format is based on the CIS as defined by the PCMCIA/SD Card Association. The CIS data contains the hardware header followed by one or more data blocks (tuples), where each tuple contains the type, length, and the value of the tuple (see Appendix A: "CIS Map," on page 33 for details).

The SDIO hardware header string must be present at the beginning of the OTP binary map and must precede all NVRAM variables. When a driver detects content in the OTP memory, the SDIO hardware header is required to boot up the BCM4339 via the SDIO interface. Therefore, the SDIO hardware header must include the minimum set of parameters necessary to program the OTP memory.

The SDIO hardware header is described in Table 6 on page 28. All other parameters that need to be programmed into the OTP memory are added after the SDIO hardware header (see "Creating and Editing the OTP Binary Map" on page 28).

When an OTP binary map contains only the SDIO hardware header, the binary map is called a minimum OTP binary map.

Table 3 describes the minimum OTP binary map for the BCM4339, which is terminated at 0xff 0xff.

Table 3: BCM4339 Minimum OTP Binary Map (502 Bytes)

Offset	0x0	0x1	0x2	0x3	0x4	0x5	0x6	0x7	0x8	0x9	0xa	0xb	0xc	0xd	0xe	0xf
0x0000	4b	00	ff	ff	00	00	20	04	d0	02	39	43	00	00	00	00
0x0010	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0020	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0030	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0040	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0050	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0060	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0070	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0080	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x0090	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00a0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00b0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00c0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00d0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00e0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00f0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00100	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00110	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00120	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00130	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00140	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00150	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00160	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00170	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00180	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x00190	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001a0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001b0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001c0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001d0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001e0	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00	00
0x001f0	00	00	00	00	ff	ff										

Programming Basic Parameters into OTP Memory

Parameters in the nvram.txt file that are to be programmed into the OTP memory must be entered in the OTP binary map after the SDIO hardware header. A CIS tuple is required for each parameter in the CIS structure. Most parameters in the nvram.txt file have a unique identifier called the CIS tuple tag. The driver recognizes and parses each CIS tuple by its tag number. For a list of the CIS tuples and associated tag numbers, see Appendix A: "CIS Map," on page 33.

Table 4 lists the basic NVRAM parameters, the associated tag number, and the number of bytes each parameter occupies in the OTP memory. Basic parameters typically have fixed values specific to a particular device or board. The value of these parameters is often retained throughout the life of the device/board. For this reason, it is generally acceptable to program these basic parameters into the OTP memory early in the development, before the design is finalized.

NVRAM Parameter CIS Tuple Tag Length of Value (in Bytes) sromrev 0x00 2 boardrev 0x02 2 boardtype 0x1b 6 macaddr 0x19 ccodea 0x0a 2

Table 4: Basic NVRAM Parameters and CIS Tuple Tags

In the OTP binary map, each tuple is formed by the four fragments described in Table 5.

Fragment

Description

Indicates the beginning of a new tuple. 0x80 is specific to Broadcom tuple subtags.

Length

Defines the total size (in bytes) of the tag plus the value of the tuple that occupies the OTP memory space.

Identifies a parameter in the nvram.txt file. A tag usually takes one byte in memory.

Value

Specifies the value of the parameter in little-endian format (first byte is the least-significant byte (LSB)).

Table 5: CIS Tuple Format

For example, the following tuple is defined by the fragments that follow:

80 03 02 00 11

- 80 Beginning of a new tuple.
- 03 The tag (1 byte) and the value (2 bytes) occupy 3 bytes (total) in the OTP memory.
- 02 Tag of 0x02 is the identifier for boardrev in the nvram.txt file.
- 00 11 The value of boardrev in reverse hexadecimal byte or 0x1100.

a. The value for ccode in the nvram.txt file is in ASCII format. It must be converted to hexadecimal format before entering it into the OTP binary map (for example, "US" = "0x55 0x53").

Table 6 on page 28 provides an example OTP binary map for a BCM4339 that contains some of the nvram.txt file parameters listed in Table 4 on page 26.

Table Legend: Hardware Header
(Table 6) SROMREV (0x0b)

BOARDREV(0x1100)

BOARDTYPE(0x064 c)

MAC Address
End of Map

In this example, the value of each parameter is as follows:

Sto sign of

- sromrev = 0x0B
- boardrev=0x1100
- boardtype=0x64c
- macaddr = 66:55:44:33:22:11



Note: CIS tuples do not have to be listed in any particular order because each tuple begins with a unique identifier.



Note: OTP bytes can be written to only once. Only blank and zero-programmed bytes can be programmed during subsequent write cycles.

Offset 0x00x1 0x2 0x30x4 0x5 0x6 0x7 0x8 0x9 0xa 0xb 0xc 0xd 0xe 0xf ff ff 4b ld0 0b 0x0000 1b 4c 0x0010 0x0020 0x0030 0x0040 0x0050 0x0060 0x0070 0x0080 0x0090 0x00a0 0x00b0 0x00c0 0x00d0 0x00e0 0x00f0 0x00100 0x00110 0x00120 0x00130 0x00140 0x00150 0x00160 0x00170 0x00180 0x00190 0x001a0 0x001b0 0x001c0 0x001d0 0x001e0 0x001f0 ff

Table 6: Example BCM4339 Minimum OTP Binary Map (502 Bytes)

Creating and Editing the OTP Binary Map

Use a hexadecimal text editor to create and edit an OTP binary map. A hexadecimal text editor preserves formatting of the nvram.txt file. Writing to the OTP memory requires a bin file that fits in the OTP memory space. For the BCM4339, the maximum size of the OTP memory is 502 bytes.



Caution! Do not use Notepad to edit the nvram.txt file. Edit the nvram.txt file using a properly formatted text editor such as Notepad++ or WordPad++ to preserve the original format of the file. Using a non-formatted text editor such as Notepad could corrupt the format of the NVRAM map, causing the driver to incorrectly read the nvram.txt file.

 Add or edit each byte in the OTP binary map to populate the SDIO hardware header and the CIS tuple, as described in the OTP binary map instructions provided in "Programming Basic Parameters into OTP Memory" on page 26.



Note: The OTP binary map file (see Figure 2 on page 30) has been edited to match the example BCM4339 OTP binary map described in Table 6 on page 28.

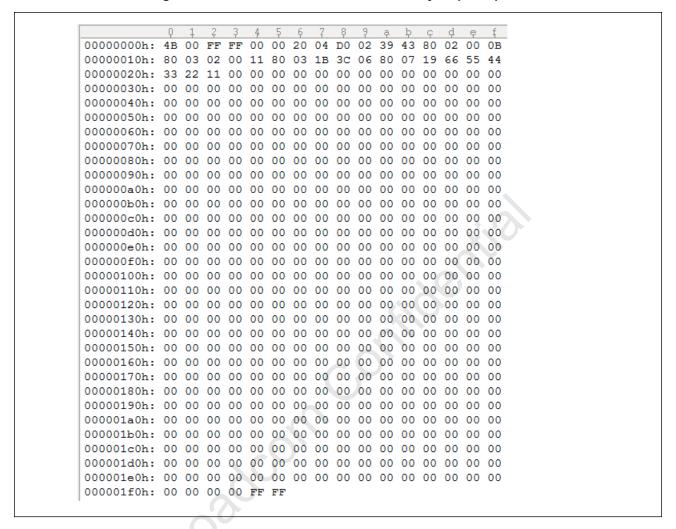
2. Save the OTP binary map as a binary image file (.bin extension) to the directory containing the wl.exe file.



Note: The file name must be save with a .bin file extension so that the data it contains can be programmed into the OTP memory. For example purposes, this file is referred to as 4339_OTP.bin in the following instructions.

Figure 2 shows the hexadecimal OTP binary map template.

Figure 2: BCM4339 Hexadecimal OTP Binary Map Template



Programming the OTP Binary Map

To program the OTP binary map for the BCM4339 using wl commands, complete the following steps:

- 1. Load the driver for the BCM4339 using the customized nvram.txt file.
- 2. Execute a few wl commands (such as wl ver) to verify that the driver installation was successful.
- 3. Execute the ciswrite 4339_OTP.bin command to program the 4339_OTP.bin to the OTP memory.
- 4. In the Windows Device Manager, disable and then enable the wireless device.
- 5. Execute the cisdump command to confirm that the OTP memory is programmed successfully.

Using 66 55 44 33 22 11 as the MAC address, the cisdump output should exactly match the OTP binary map provided on page 31.

```
[root@dhcpe6-sv1-141 ec_4339_driver]# wl cisdump
Source: 2 (Internal OTP)
Maximum length: 502 bytes
0: 0x4b 0x00 0xff 0xff 0x00 0x00 0x20 0x04
Byte
 8: 0xd0 0x02 0x39 0x43 0x80 0x02 0x00 0x0b
Byte
16: 0x80 0x03 0x02 0x00 0x11 0x80 0x03 0x1b
Byte
24: 0x4c 0x06 0x80 0x07 0x19 0x66 0x55 0x44
Byte
32: 0x33 0x22 0x11 0x00 0x00 0x00 0x00 0x00
Byte
Byte
Byte
Byte
Byte
Byte
Byte
Byte
Byte
Byte 496: 0x00 0x00 0x00 0x00 0xff 0xff
[root@dhcpe6-sv1-141 ec_4339_driver]#
```

(fiderniia)

If the cisdump matches the OTP binary map, OTP memory programming is complete. Once programmed, additional blank spaces (00) in the OTP memory can be written by filling in those corresponding blank spaces in the OTP binary map. There is no restriction on how many times a device can be programmed, provided that each programming cycle is writes to only blank, unwritten spaces.

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Follow the same procedure to program the additional blank spaces.

Appendix A: CIS Map

Table 7 and Table 8 list the CIS map (standard tuple tags and Broadcom subtags) for SDIO devices.

Table 7: Standard Tuple Tags

Name	Tag	Length	Variable	Description
CISTPL_VERS_1	0x15		manf	CIS version, manufacturer, device, and
			productname	version strings
CISTPL_MANFID	0x20	4	manfid	Manufacturer and device ID
			prodid	
CISTPL_FUNCID	0x21	_	_	Function identification
CISTPL_FUNCE	0x22	_	_	Function extensions
CISTPL_FUNCE	0x22	8	_	Subtype = FUNCE_mac(0x4)
				Value: 6 byte MAC address
CISTPL_CFTABLE	0x1b	2	regwindowsz	Configuration table entry
CISTPL_FID_SDIO	0x0c	_	_	Extensions defined by SDIO specification
CISTPL_BRCM_HNBU	0x80	_	_	Broadcom-specific tuple subtag identifier
CISTPL_END	0xff	_	_	End of the CIS tuple chain

Table 8: Broadcom Tuple Subtags

Name	Tag	Length	Variable	Description
HNBU_SROMREV	0x00	1	sromrev	SROM revision
HNBU_CHIPID	0x01	4/6/8/10	vendid	PCI vendor and device IDs
			devid	
			chiprev	
			subvendid	
			subdevid	
			boardtype	
HNBU_BOARDREV	0x02	1/2	boardrev	Board revision
HNBU_AA	0x06	1/2	aa2g	Antennas available
			aa5g	
HNBU_BOARDFLAGS	0x08	2/4/6	boardflags	Board flags
HNBU_CCODE	0x0a	3	ccode	Country code (2 bytes ASCII + 1
			cctl	byte cctl) in rev 2.
				The cctl means indoor/outdoor, but it is never used.
HNBU_ANT5G	0x0f	2	aa5g, ag1	5G antennas available/gain
HNBU_XTALFREQ	0x13	4	xtalfreq	Crystal frequency (kilohertz)
HNBU_BOARDNUM	0x18	2	boardnum	Board serial number (independent of MAC address)

Table 8: Broadcom Tuple Subtags (Cont.)

Name	Tag	Length	Variable	Description
HNBU_MACADDR	0x19	6	macaddr	MAC address override for the standard CIS LAN_NID
HNBU_BOARDTYPE	0x1b	2	boardtype	Board type
HNBU_REGREV	0x22	1	regrev	-
HNBU_FEM	0x23	2/4	antswctl2g(15-11)	-
			triso2g(10-8)	
			pdetrange2g(7-3)	
			extpagain2g(2-1)	
			tssipos2g(0)	
			antswctl5g(15-11)	
			triso5g(10-8)	
			pdetrange5g(7-3)	. (2)
			extpagain5g(2-1)	
			tssipos5g(0)	
HNBU_CCKFILTTYPE	0x36	1	cckdigfilttype	CCK digital filter selection option
HNBU_CCKBW202GP	0x41	4(max)	cckbw202gpo cckbw20ul2gpo	CCK Power offsets for 20 MHz rates (11, 5.5, 2, 1 Mbps)
HNBU_MCS5GLPO	0x45	12(max)	mcsbw205glpo	MCS 0-7 power-offset
TINDO_IVICS3GLFO	0.43	12(11101)	mcsbw20ul5glpo	LSB Nibble: m0
			mcsbw405glpo	
LINDU MOOFOMDO	0.40	40/		MSB nibble: m7
HNBU_MCS5GMPO	0x46	12(max)	mcsbw205gmpo	MCS 0-7 power-offset
			mcsbw20ul5gmpo	LSB Nibble: m0
			mcsbw405gmpo	MSB Nibble: m7
HNBU_MCS5GHPO	0x47	12(max)	mcsbw205ghpo	MCS 0-7 power-offset
			mcsbw20ul5ghpo	LSB Nibble: m0
			mcsbw405ghpo	MSB Nibble: m7
HNBU_MUXENAB	0x56	1	muxenab	Enable mux options
HNBU_ACPA_C0	0x59	38	subband5gver	Subband 5GHz
			maxp2ga0	Maximum power, PA
			pa2ga0	parameters for chain 0
			maxp5ga0	
			pa5ga0	
HNBU_ACPPR_2GPO	0x5e	4	dot11agofdmhrbw202gpo ofdmlrbw202gpo	2G power offsets

Table 8: Broadcom Tuple Subtags (Cont.)

Name	Tag	Length	Variable	Description
HNBU_ACPPR_5GPO	0x5f	30	mcsbw805glpo	5G power offsets
			mcsbw1605glpo	
			mcsbw805gmpo	
			mcsbw1605gmpo	
			mcsbw805ghpo	
			mcsbw1605ghpo	
			mcslr5glpo	
			mcslr5gmpo	
			mcslr5ghpo	
HNBU_ACPPR_SBPO	0x60	32	sb20in40hrpo	Subband power offsets
			sb20in80and160hr5glpo	
			sb40and80hr5glpo	. (2)
			sb20in80and160hr5gmpo	
			sb40and80hr5gmpo	
			sb20in80and160hr5ghpo	
			sb40and80hr5ghpo	
			sb20in40lrpo	
			sb20in80and160lr5glpo	
			sb40and80lr5glpo	
			sb20in80and160lr5gmpo	
			sb40and80lr5gmpo	
			sb20in80and160lr5ghpo	
			sb40and80lr5ghpo	
			dot11agduphrpo	
			dot11agduplrpo	
HNBU_AGBGA	0x63	6	agbg0	Antenna gain A and G band
			agbg1	
			agbg2	
			aga0	
			aga1	
			aga2	

Table 8: Broadcom Tuple Subtags (Cont.)

Name	Tag	Length	Variable	Description
HNBU_ACRXGAINS_C	0x67	4	rxgains for chain 1 (rxgains5gtrelnabypa0 rxgains5gtrisoa0 rxgains5gelnagaina0 rxgains2gtrelnabypa0 rxgains2gtrisoa0 rxgains2gelnagaina0 rxgains5ghtrelnabypa0 rxgains5ghtrisoa0 rxgains5ghelnagaina0 rxgains5gmtrelnabypa0 rxgains5gmtrelnabypa0 rxgains5gmtrelnabypa0 rxgains5gmtrelnabypa0 rxgains5gmtrelnabypa0 rxgains5gmtrisoa0 rxgains5gmelnagaina0)	Word offset 112, 113
HNBU_TEMPTHRESH	0x3A	2/6	tempthresh 1byte temps_hysteresis 4 bits temps_period 4 bits tempoffset 8 bits tempsenseslope 8 bits tempcorrx 6 bits, tempsense_option 2 bits phycaltempdelta	Sets the values for temperature threshold, period, and hysteresis.
HNBU_ACPAPARAM	0x84	85	pa2ga0 pa5pa0 pa2gccka0 pa5gbw40a0 pa5gbw80a0	Enables PA trimming WAR for multiple BW support.

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E-mail: info@broadcom.com Web: www.broadcom.com

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